MA6X128 (MA128)

Silicon epitaxial planar type

For switching circuits

■ Features

- Four isolated elements contained in one package, allowing highdensity mounting
- Centrosymmetrical wiring, allowing to free from the taping direction
- The mirror image wiring of MA6X123 (MA123)
- Short reverse recovery time t_{rr}
- Small terminal capacitance C_t
- High breakdown voltage: $V_R = 80 \text{ V}$

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Reverse voltage	V_R	80	V
Maximum peak reverse voltage	V_{RM}	80	V
Forward current *1	I_{F}	100	mA
Peak forward current *1	I_{FM}	225	mA
Non-repetitive peak forward	I _{FSM}	500	mA
surge current *1, 2			
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C ()

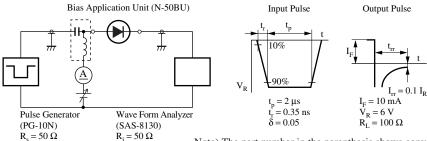
Note) *1: Value for single diode

*2: t = 1 s

■ Electrical Characteristics T_a = 25°C ± 3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	$V_{\rm F}$	$I_F = 100 \text{ mA}$	1.90		1.2	V
Reverse voltage	V_R	$I_R = 100 \mu A$	80			V
Reverse current	I_R	V _R = 75 V			100	nA
Terminal capacitance	C _t	$V_R = 0 V, f = 1 MHz$			2	pF
Reverse recovery time *	t _{rr}	$I_F = 10 \text{ mA}, V_R = 6 \text{ V}$			3	ns
MSI.		$I_{rr} = 0.1 I_R, R_L = 100 \Omega$				

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
 - 2. Absolute frequency of input and output is 100 MHz.
 - 3. *: t_{rr} measurement circuit



Unit: mm

2.90*0.05
1.9±0.1
(0.95) (0.95) (0.95)

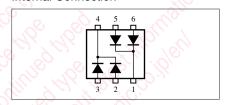
3 2 0.30*0.05

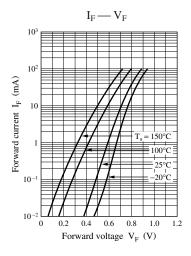
10 (6.95) (0.9

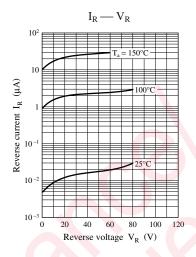
Marking Symbol: M2V

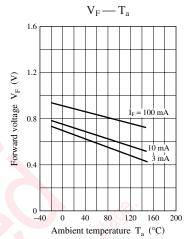
Internal Connection

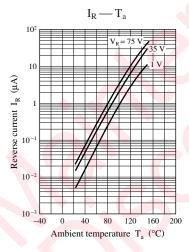
Note) The part number in the parenthesis shows conventional part number.

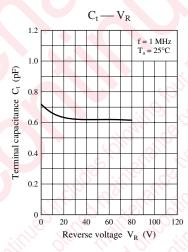


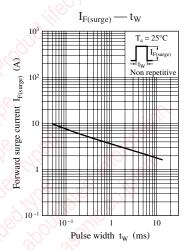












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